MOSFETs Silicon N-channel MOS (U-MOSⅨ-H)

TK5R1P08QM

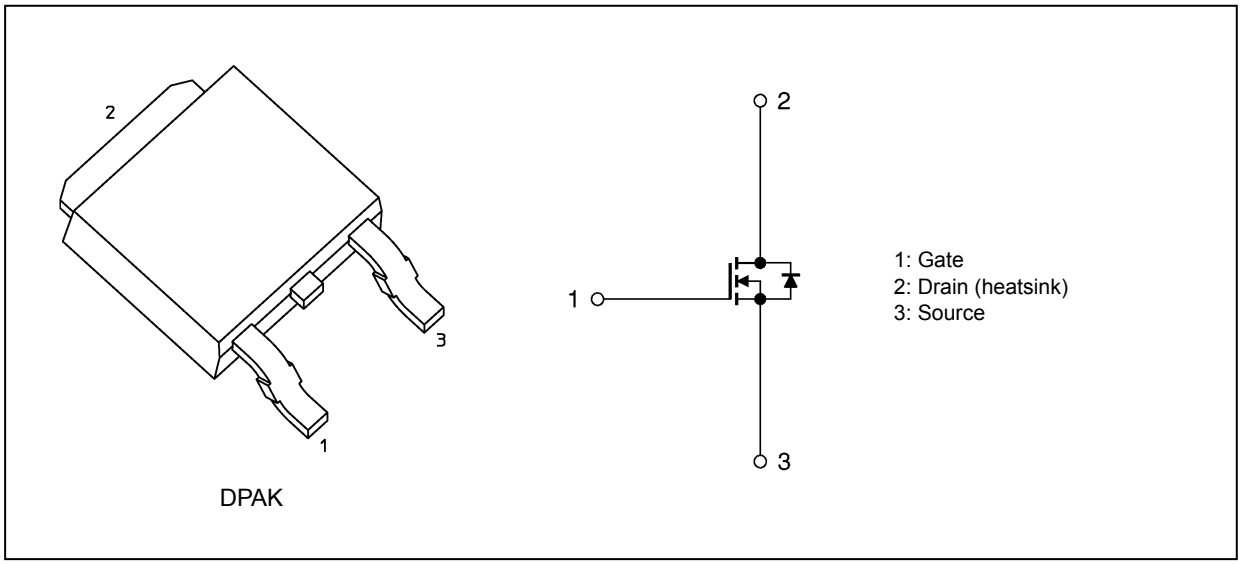
1. Applications

- High-Efficiency DC-DC Converters
- Switching Voltage Regulators
- Motor Drivers

2. Features

(1) High-speed switching
(2) Small gate charge: Q_{SW} = 17 nC (typ.)
(3) Small output charge: Q_{oss} = 66 nC (typ.)
(4) Low drain-source on-resistance: $R_{DS(ON)}$ = 4.2 mΩ (typ.) (V_{GS} = 10 V)
(5) Low leakage current: I_{DSS} = 10 μA (max) (V_{DS} = 80 V)
(6) Enhancement mode: V_{th} = 2.5 to 3.5 V (V_{DS} = 10 V, I_D = 0.7 mA)

3. Packaging and Internal Circuit



Start of commercial production
2021-01

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4. Absolute Maximum Ratings (Note) (T_a = 25 °C unless otherwise specified)

Characteristics			Symbol	Rating	Unit
Drain-source voltage			V_{DSS}	80	V
Gate-source voltage			V_{GSS}	±20	
Drain current (DC)	(T_c = 25 °C)	(Note 1)	I_D	84	A
Drain current (DC)	(Silicon limit)	(Note 1), (Note 2)	I_D	105	
Drain current (pulsed)	(t = 100 μs)	(Note 1)	I_{DP}	298	
Power dissipation	(T_c = 25 °C)		P_D	104	W
Single-pulse avalanche energy		(Note 3)	E_{AS}	33	mJ
Single-pulse avalanche current		(Note 3)	I_{AS}	84	A
Channel temperature			T_{ch}	175	°C
Storage temperature			T_{stg}	-55 to 175	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

5. Thermal Characteristics

Characteristics		Symbol	Max	Unit
Channel-to-case thermal resistance	(T_c = 25 °C)	$R_{th(ch-c)}$	1.43	°C/W

Note 1: Ensure that the channel temperature does not exceed 175 °C.
Note 2: Limited 84 A by package capability
Note 3: V_{DD} = 64 V, T_{ch} = 25 °C (initial), L = 3.7 μH, I_{AS} = 84 A

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

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6. Electrical Characteristics

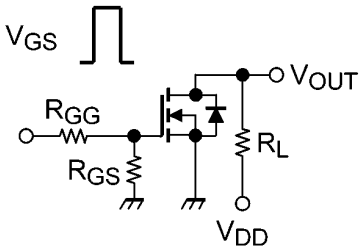
6.1. Static Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	I_{GSS}	V_{GS} = ±20 V, V_{DS} = 0 V	—	—	±0.1	μA
Drain cut-off current	I_{DSS}	V_{DS} = 80 V, V_{GS} = 0 V	—	—	10	
Drain-source breakdown voltage	$V_{(BR)DSS}$	I_D = 10 mA, V_{GS} = 0 V	80	—	—	V
Drain-source breakdown voltage (Note 4)	$V_{(BR)DSX}$	I_D = 10 mA, V_{GS} = -20 V	60	—	—	
Gate threshold voltage	V_{th}	V_{DS} = 10 V, I_D = 0.7 mA	2.5	—	3.5	
Drain-source on-resistance	$R_{DS(ON)}$	V_{GS} = 6 V, I_D = 20 A	—	5.2	7.0	mΩ
		V_{GS} = 10 V, I_D = 42 A	—	4.2	5.1	

Note 4: If a reverse bias is applied between gate and source, this device enters $V_{(BR)DSX}$ mode. Note that the drain-source breakdown voltage is lowered in this mode.

6.2. Dynamic Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Input capacitance	C_{iss}	V_{DS} = 40 V, V_{GS} = 0 V, f = 1 MHz	—	3980	—	pF
Reverse transfer capacitance	C_{rss}		—	55	—	
Output capacitance	C_{oss}	V_{DS} = 40 V, V_{GS} = 0 V, f = 1 MHz	—	1000	—	
Gate resistance	r_g	—	—	1.6	2.4	Ω
Switching time (rise time)	t_r	See Fig. 6.2.1	—	64	—	ns
Switching time (turn-on time)	t_{on}		—	83	—	
Switching time (fall time)	t_f		—	68	—	
Switching time (turn-off time)	t_{off}		—	119	—	



V_{DD} ≈ 40 V
V_{GS} = 0 V/ 10 V
I_D = 42 A
R_L = 0.95 Ω
R_{GG} = 4.7 Ω
R_{GS} = 4.7 Ω
Duty ≤ 1 %, t_w = 10 μs

Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Q_g	V_{DD} ≈ 40 V, V_{GS} = 10 V, I_D = 42 A	—	56	—	nC
		V_{DD} ≈ 40 V, V_{GS} = 6 V, I_D = 20 A	—	34	—	
Gate-source charge 1	Q_{gs1}	V_{DD} ≈ 40 V, V_{GS} = 10 V, I_D = 42 A	—	17	—	
Gate-drain charge	Q_{gd}		—	12	—	
Gate switch charge	Q_{SW}		—	17	—	
Output charge	Q_{oss}	V_{DS} = 40 V, V_{GS} = 0 V, f = 1 MHz	—	66	—	

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6.4. Source-Drain Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Reverse drain current (pulsed) (Note 5)	I_{DRP} (t = 100 μs)	—	—	—	298	A
Diode forward voltage	V_{DSF}	I_{DR} = 42 A, V_{GS} = 0 V	—	—	-1.2	V
Reverse recovery time	t_{rr}	I_{DR} = 21 A, V_{GS} = 0 V, $-dI_{DR}/dt$ = 100 A/μs	—	48	—	ns
Reverse recovery charge	Q_{rr}		—	53	—	nC

Note 5: Ensure that the channel temperature does not exceed 175 °C.

7. Marking

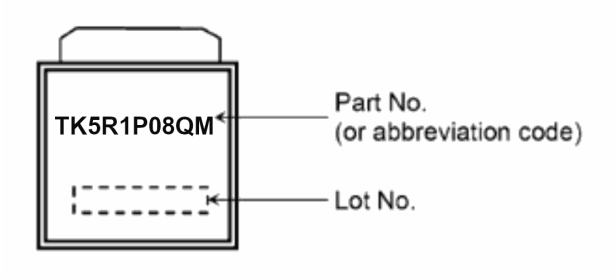


Fig. 7.1 Marking

8. Characteristics Curves (Note)

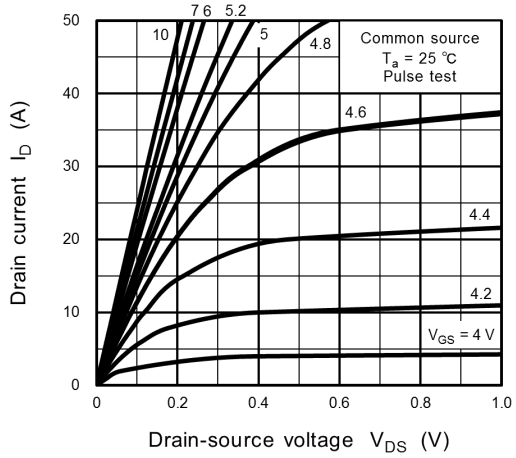


Fig. 8.1 I_D - V_{DS}

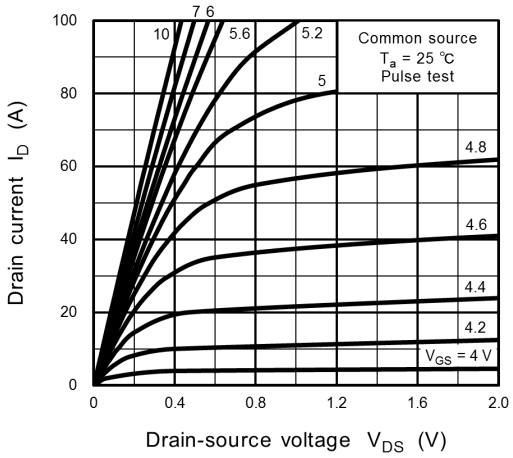


Fig. 8.2 I_D - V_{DS}

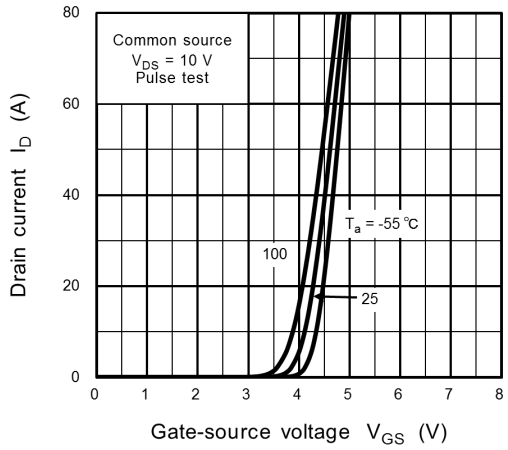


Fig. 8.3 I_D - V_{GS}

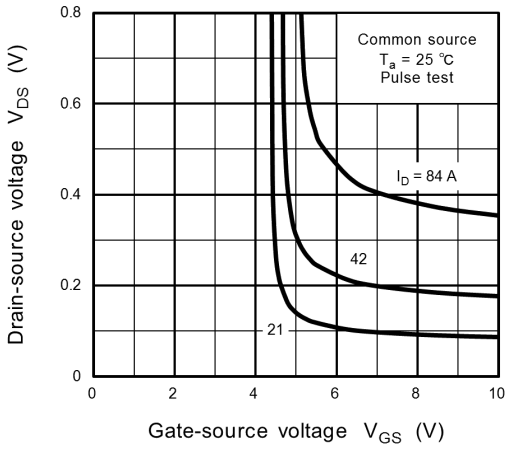


Fig. 8.4 V_{DS} - V_{GS}

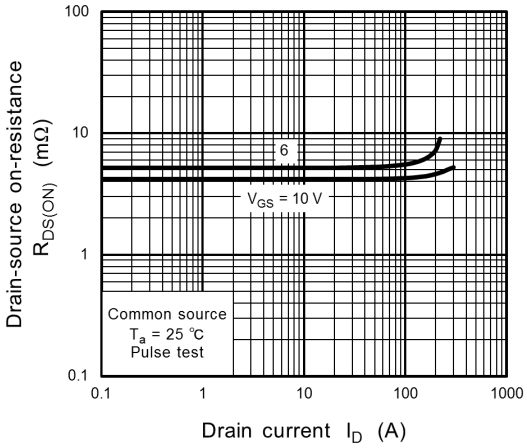


Fig. 8.5 $R_{DS(ON)}$ - I_D

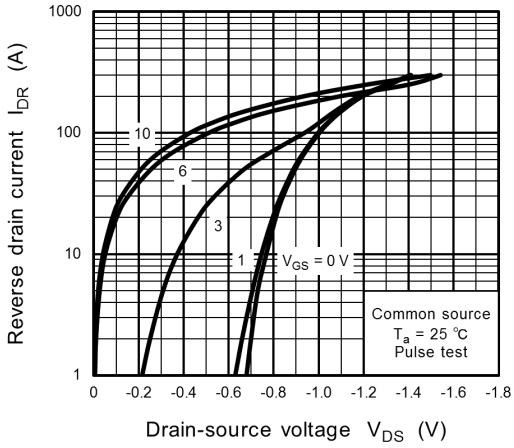


Fig. 8.6 I_{DR} - V_{DS}

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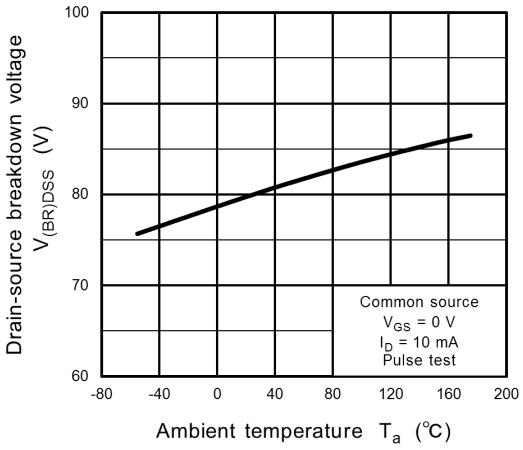


Fig. 8.7 $V_{(BR)DSS}$ - T_a

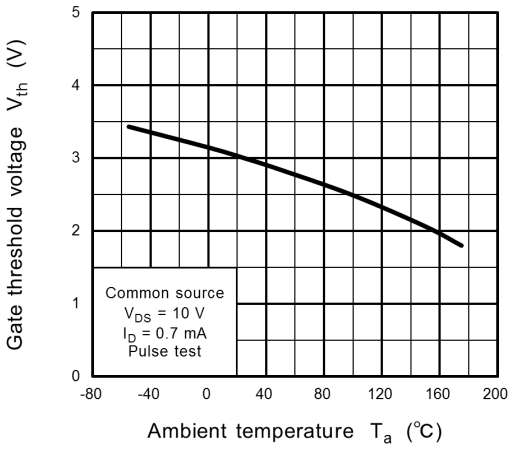


Fig. 8.8 V_{th} - T_a

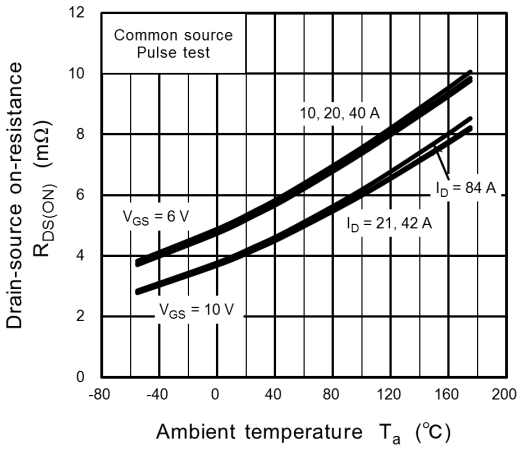


Fig. 8.9 $R_{DS(ON)}$ - T_a

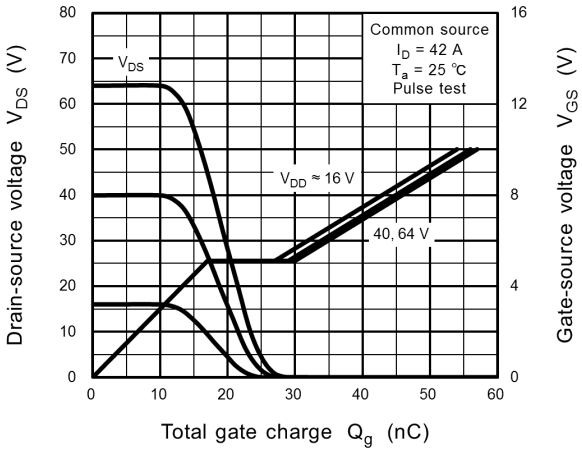


Fig. 8.10 Dynamic Input/Output Characteristics

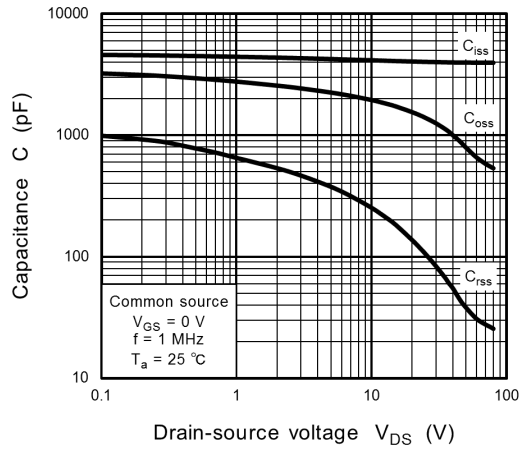


Fig. 8.11 Capacitance - V_{DS}

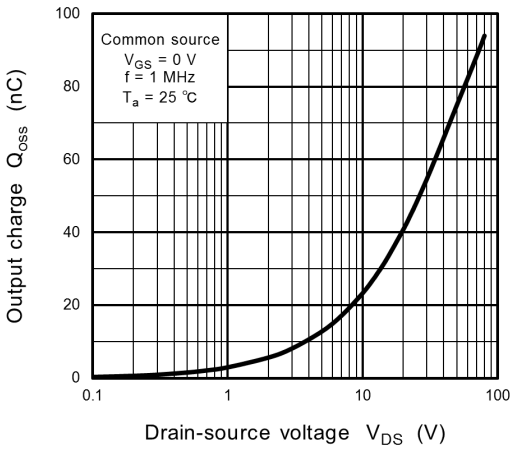


Fig. 8.12 Q_{oss} - V_{DS}

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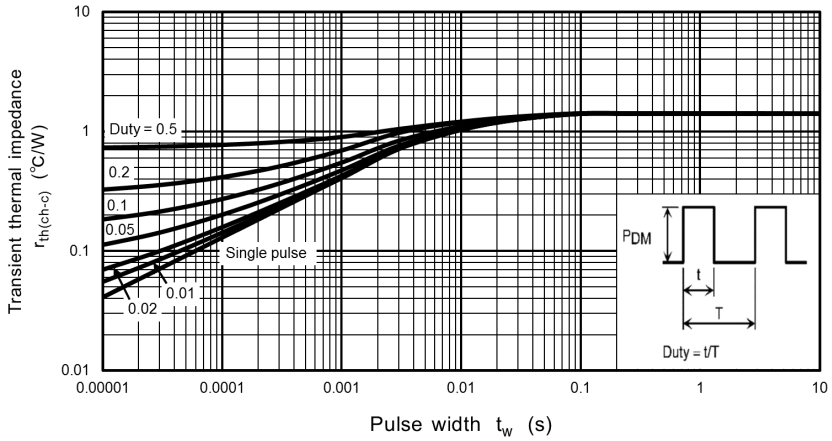


Fig. 8.13 r_{th} - t_w
(Guaranteed Maximum)

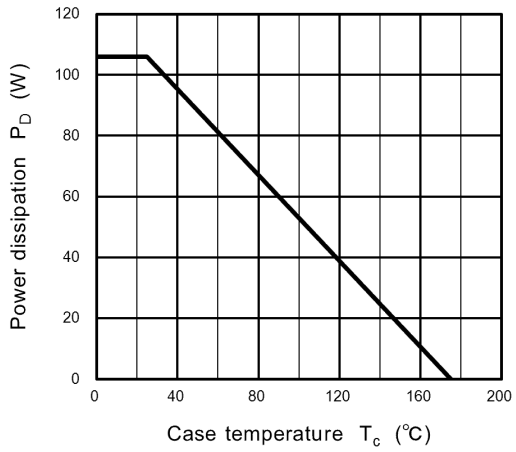


Fig. 8.14 P_D - T_c
(Guaranteed Maximum)

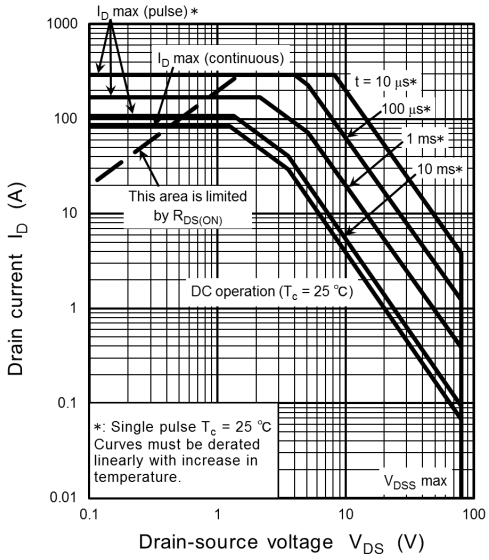
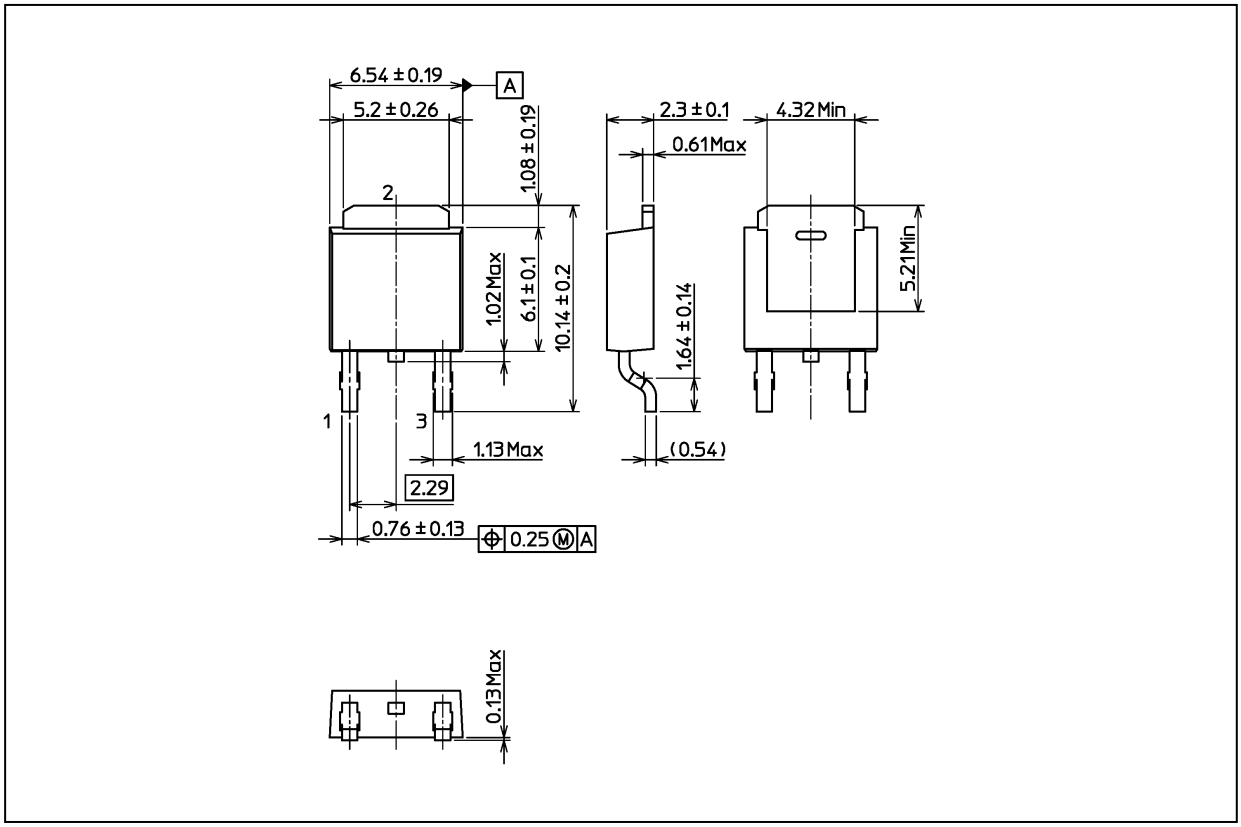


Fig. 8.15 Safe Operating Area
(Guaranteed Maximum)

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Package Dimensions

Unit: mm



Weight: 0.33 g (typ.)

Package Name(s)
TOSHIBA: 2-7N1S
Nickname: DPAK

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